

Chapter 6 Specifications

All measurements are performed at 25 °C unless stated otherwise.

Electrical Specifications		
Parameter	Symbol	Value
Detector	-	InGaAs PIN
Active Area Diameter	-	Ø80 µm
Wavelength Range	λ	800 to 1700 nm
Peak Wavelength	λ_p	1550 nm
Peak Response ²	$\mathfrak{R}(\lambda_p)$	0.90 A/W (Typ.)
Diode Capacitance	C_J	0.3 pF
Bandwidth ^{2,3,4} (-3 dB)	-	5 GHz
Rise Time ^{2,3,4} (20/80%) @ 952 nm	-	70 ps (Typ.)
Fall Time ^{2,3,4} (80/20%) @ 952 nm	-	110 ps (Typ.)
NEP (λ_p) @ 1550 nm	-	2×10^{-15} W/Hz ^{1/2}
Output Voltage ⁵	V_{OUT}	2 V (Max)
After-Pulse Ringing	-	<20% of Maximum
Bias Voltage	V_R	12 V
Dark Current ^{2,6}	I_D	1.5 nA
General		
Input	FC/PC Fiber Connector	
Output	SMA (DC Coupled)	
Package Size	2.21" x 1.40" x 0.80" (56.1 mm x 35.6 mm x 20.3 mm)	
Ball Lens Diameter	0.059" (1.50 mm)	
Ball Lens Clear Aperture	Ø0.8 mm	
Weight	0.18 kg	
Storage Temp	0 to 40 °C	
Operating Temp	0 to 40 °C	
Battery	A23, 12 V _{DC} , 40 mAh	
Replacement Battery	Energizer No. A23	

Bandwidth is defined as the boundary at which the output of the circuit is 3 dB below the nominal output.

² Measured with a specified bias voltage of 12 V.

³ For a 50 Ω Load

⁴ Low battery voltage will result in slower rise times and decreased bandwidth.

⁵ A higher output voltage will decrease the bandwidth.

⁶ For a 1 MΩ Load